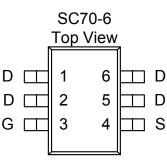
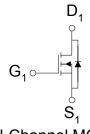
## N-Channel 40V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SC70-6 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY			
<b>V</b> <sub>DS</sub> (V)	$V_{DS}(V)$ $r_{DS(on)}(\Omega)$ $I_D(A)$		
40	$0.086 @V_{C8} = 10 V$	3.5	
	$0.128 @V_{CS} = 4.5V$	2.9	





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage		V <sub>DS</sub>	40	V	
Gate-Source Voltage		Vas	±20	v	
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	I.	3.5	А	
	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	ъD	2.9		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	±20		
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	1.6	Α	
	$T_A=25^{\circ}C$	D	1.56	W	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	I D	0.81		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Ambient <sup>a</sup>	t <= 5 sec	D	100	<sup>0</sup> 0/III	
	Steady-State	$R_{THJA}$	166	C/W	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
D	Gendad	To at Constitution	Limits			TI.4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	IGSS	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA	
Zero Gate Voltage Drain Gurrent	IDSS	$V_{DS} = 32 V, V_{GS} = 0 V$			1	uA	
-	1055	$V_{DS} = 32 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			10	uA	
On-State Drain Current <sup>A</sup>	ID(on)	$V_{DS} = 5 V, V_{GS} = 4.5 V$	10			Α	
		$V_{GS} = 10 V$ , $I_D = 3.5 A$			86	mΩ	
Drain-Source On-Resistance <sup>A</sup>	TDS(on)	$V_{GS} = 4.5 V_2 I_D = 2.9 A$			128		
Forward Tranconductance <sup>A</sup>	gś	$V_{DS} = 10 V$ , $I_D = 3.5 A$		11.3		S	
Diode Forward Voltage	Vsd	$I_{\rm S} = 1.6  \text{A}, V_{\rm GS} = 0  \text{V}$		0.75		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	$V_{DS} = 10 V, V_{CS} = 4.5 V, I_D = 3.5 A$		7.5		nC	
Gate-Source Charge	Qgs			0.6			
Gate-Drain Charge	Qgd			1.0			
Input Capacitance	Gss	$V_{DS} = 15 V, V_{GS} = 0 V, \qquad f$ $= 1 M Hz$		720		pF	
Output Capacitance	Coss			165			
Reverse Transfer Capacitance	Grss			60			
Tum-On Delay Time	td(on)			8			
Rise Time	tr	$V_{DD} = 10 V, R_L = 15 \Omega, I_D = 1 A, V_{GEN} = 4.5 V$		24		ns	
Tum-Off Delay Time	td(off)			35			
Fall-Time	tf			10		I	

Notes

a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .

b. Guaranteed by design, not subject to production testing.

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